

BIPOLAR ANALOG INTEGRATED CIRCUIT μ PC814

DUAL J-FET INPUT LOW-OFF SET OPERATIONAL AMPLIFIER

DESCRIPTION

Dual operational amplifier μ PC814 is a high-speed version of the μ PC812. NEC's unique high-speed PNP transistor (fr = 300 MHz) in the output stage yields a high slew rate of 25 V/ μ s under voltage-follower conditions without an oscillation problem. Zener-zap resistor trimming in the input stage produces excellent offset voltage and temperature drift characteristics.

Having AC performance characteristics that are two times better than conventional bi-FET op amps, the μ PC814 is ideal for fast integrators, active filters, and other high-speed circuit applications.

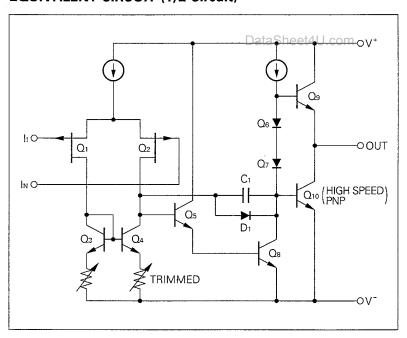
FEATURES

- High slew rate: 25 V/μs (TYP.)
- Stable operation with 220 pF capacitive load
- Low input offset voltage ±3 mV (MAX.)

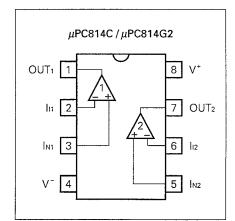
 $\pm 7 \mu V/^{\circ}C$ (TYP.) temperature drift

- Very low input bias and offset currents
- Low noise: $e_n = 19 \text{ nV}/\sqrt{\text{Hz}}$ (TYP.)
- Output short circuit protection
- High input impedance ... J-FET Input Stage
- Internal frequency compensation

EQUIVALENT CIRCUIT (1/2 Circuit)



CONNECTION DIAGRAM (Top View)



ORDERING INFORMATION

PART NUMBER	PACKAGE	QUALITY GRADE
μPC814C	8 PIN PLASTIC DIP (300 mil)	Standard
μPC814G2	8 PIN PLASTIC SOP (225 mil)	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by

DataSheet4U.com NEC Corporation to know the specification of quality grade on the devices and its recommended approximal heet 4U.com

Document No. IC-1983A (O.D. No. IC-6795) Date Published March 1993 M Printed in Japan



ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

PARAMETER		SYMBOL	μPC814	UNIT	
Voltage between V ⁺ and V ⁻ (Note 1)		V+ - V-	-0.3 to +36	V	
Differential Input Voltage		Vid	±30	V	
Input Voltage		(Note 2)	Vı	V0.3 to V+ +0.3	V
Output Voltage (Note 3)		Vo	V0.3 to V+ +0.3	V	
Davis Dississis	C Package	(Note 4)	PT	350	mW
Power Dissipation	G2 Package	(Note 5)	PT	440	mW
Output Short Circuit Duration (Note 6)			Indefinite	sec	
Operating Temperature Range		Topt	-40 to +85	°C	
Storage Temperature Range		·Tstg	.Tstg -55 to +125		

- Note 1. Reverse connection of supply voltage can cause destruction.
- Note 2. The input voltage should be allowed to input without damage or destruction. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.
- Note 3. This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.
- Note 4. Thermal derating factor is -5.0 mV / °C when ambient temperature is higher than 55 °C.
- Note 5. Thermal derating factor is -4.4 mV / °C when ambient temperature is higher than 25 °C.
- **Note 6.** Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4 and Note 5.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V [±]	± 5		± 16	V
Output Current	lo			± 10	mA
Capacitive Load (A ₀ = +1, R _f = 0 Ω)	CL			220	pF

DataShe

et4U.com

ELECTRICAL CHARACTERISTICS ($T_a = 25$ °C, $V^{\pm} = \pm 15$ V)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Input Offset Voltage	Vio		±1	±2.5	mV	Rs ≤ 50 Ω
Input Offset Current (Note 7)	lio		±25	±100	pA	
Input Bias Current (Note 7)	Ів		50	200	pА	
Large Signal Voltage Gain	Αυ	25	200		V/mV	$RL \ge 2 k\Omega$, $Vo = \pm 10 V$
Supply Current	Icc		2.5	3.4	mA	lo = 0 A, Both Amplifier
Common Mode Rejection Ratio	CMR	70	100		dB	
Supply Voltage Rejection Ratio	SVR	70	100		dB	
Output Voltage Swing	Vom	±12	+14.0 -13.3		V	RL ≥ 10 kΩ
Output Voltage Swing	Vom	±10	+13.5 -12.8		V	RL ≥ 2 kΩ
Common Mode Input Voltage Range	Vicм	±11	+14 -12		V	
Slew Rate	SR		15		V/μs	A _υ =1
Unity Gain Frequency	funity		4		MHz	
Input Equivalent Noise Voltage Density	e n		19		nV/√Hz	Rs = 100 Ω, f = 1 kHz
Channel Separation			120		dB	
Input Offset Voltage	Vio	ataShee	et4LL.com	±5	mV	Rs \leq 50 Ω , T _a = -20 to +70 °C
Average Vio Temperature Drift	⊿Vio/⊿T		±7		μV/°C	Ta = -20 to +70 °C
Input Offset Current (Note 7)	lio			±2	nA	Ta = -20 to +70 °C
Input Bias Current (Note 7)	Ів			7	nA	Ta = -20 to +70 °C

et4U.com

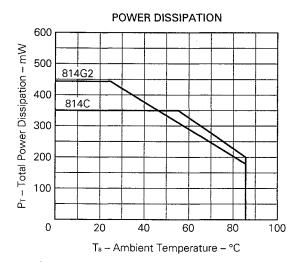
DataShe

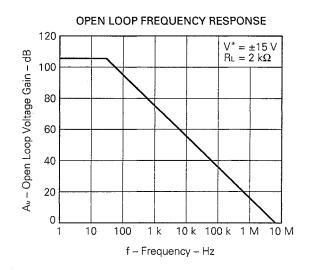
Note 7. Input bias currents flow into IC. Because each currents are gate leak current of P-channel J-FET on input stage.

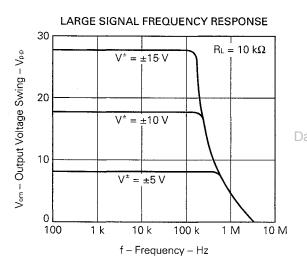
And that are temperature sensitive. Short time measuring method is recommendable to maintain the junction temperature close to the ambient temperature.

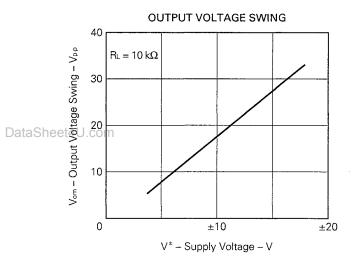
www.DataSheet4U.com

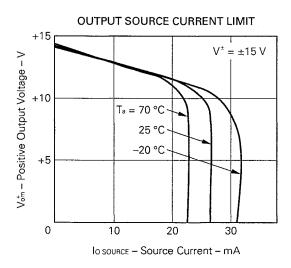
TYPICAL PERFORMANCE CHARACTERISTICS (Ta = 25 °C, TYP.)

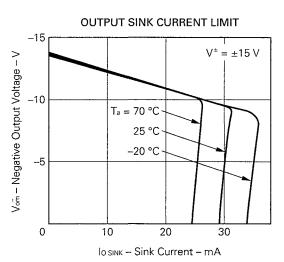








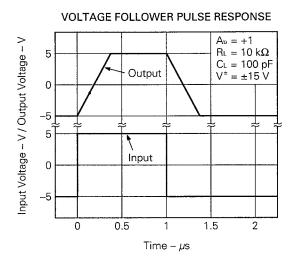


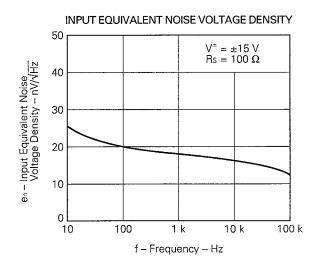


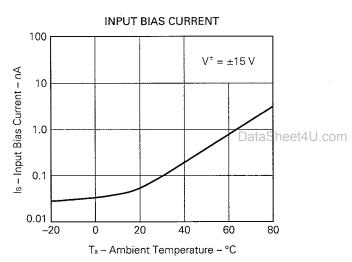
DataSheet4U.com

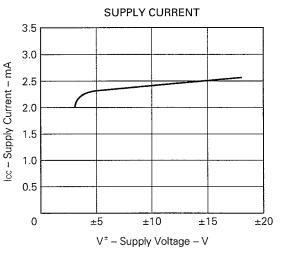
et4U.com

www.DataSheet4U.com









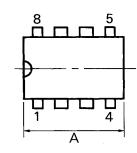
et4U.com

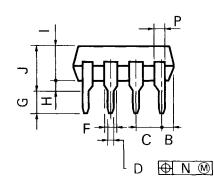
DataSheet4U.com

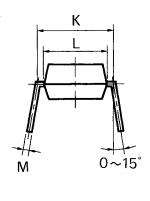
www.DataSheet4U.com



8PIN PLASTIC DIP (300 mil)







P8C-100-300B,C

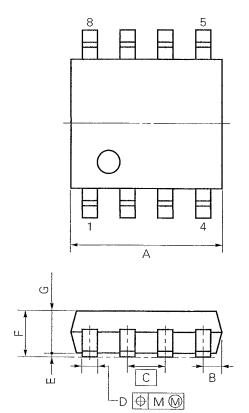
NOTES

et4U.com

- Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

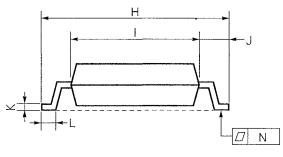
ITEM	MILLIMETERS	INCHES
Α	10.16 MAX.	0.400 MAX.
В	1.27 MAX.	0.050 MAX.
DataS	neet4l2.54r(T.P.)	0.100 (T.P.)
D	0.50 + 0.10	0.020 - 0.004
F	1.4 MIN.	0.055 MIN.
G	3.2 +0.3	0.126 ±0.012
Н	0.51 MIN.	0.020 MIN.
1	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
К	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
М	0.25 + 0.10	0.010 -0.003
N	0.25	0.01
Р	0.9 MIN.	0.035 MIN.

8 PIN PLASTIC SOP (225 mil)



detail of lead end





DataSheet4U.com

S8GM-50-225B-2

		58GIVI-50-225B-2
ITEM	MILLIMETERS	INCHES
А	5.37 MAX.	0.212 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	0.016+0.004
Е	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071MAX.
G	1.49	0.059
Н	6.5±0.3	0.256±0.012
I	4.4	0.173
J	1.1	0.043
K	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.002}$
L	0.6±0.2	0.024+0.008
М	0.12	0.005
N	0.15	0.006

NOTE

et4U.com

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

DataSheet4U.com

www.DataSheet4U.com



RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (IEI-1207).

[μPC814G2]

Soldering method	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	IR30-00-1
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 1, Exposure limit*: None	VP15-001
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below, Number of flow process: 1, Exposure limit*: None	WS15-00-1
Partial heating method	Terminal temperature: 300 °C or below, Flow time: 10 seconds or below, Exposure limit*: None Data Sheet 4U.com	

^{*:} Exposure limit before soldering after dry-pack package is opened. Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method."

TYPES OF THROUGH HOLE DEVICE

[μPC814C]

et4U.com

Soldering method	Soldering conditions	Recommended condition symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

[MEMO]

DataShe

DataSheet4U.com

DataSheet4U.com

et4U.com

www.DataSheet4U.com



[MEMO]

et4U.com

No part of this document may be copied or reproduced in any from or by any means without the prior written consent of NEC Corporation.NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

The devices listed in this document are not suitable for use in aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or they intend to use "Standard" quality grade NEC devices for applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

M4 92.6

www.DataSheet4U.com